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Sheet

Complete if Known
Application Number
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First Named Inventor
Nak-Kyte Park
Art Unit
Examiner Name
Owind Law
Attorney Docket Number
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Examiner Initiats*	Cite No.1	Document Number  Number - Kind Code <sup>2</sup> (if known)	Publication Date or Issue Date MM-OD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear			
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Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taylor & Zafman (w/r) 08/11/2003.